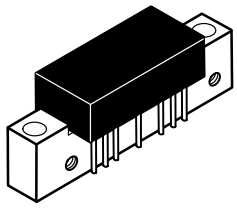
The RF Line
600 MHz CATV Amplifier Module

MHW6222-6

This module is designed specifically for 600 MHz CATV applications. Features ion–implanted arsenic emitter transistors with 7 GHz f_T and an all gold metallization system.

- Specified for 87–Channel Performance
- Broadband Power Gain — @ f = 40–600 MHz
  G_p = 21 dB (Min) @ 50 MHz
  21.7 dB (Min) @ 600 MHz
- Broadband Noise Figure @ 600 MHz
  NF = 6 dB (Max)
- Superior Gain, Return Loss and DC Current Stability with Temperature
- All Gold Metallization
- 7 GHz Ion–Implanted Transistors

5TH GENERATION
22 dB GAIN
600 MHz
87–CHANNEL
CATV INPUT/OUTPUT
TRUNK AMPLIFIERS



CASE 714–06, STYLE 1

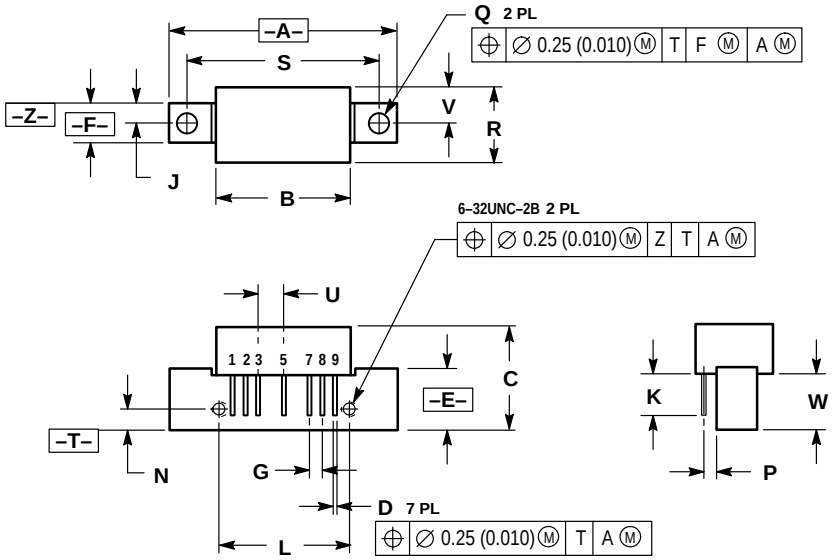
ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
RF Voltage Input	V_{in}	+60	dBmV
DC Supply Voltage	V_{CC}	+28	Vdc
Operating Case Temperature Range	T_C	–20 to +100	°C
Storage Temperature Range	T_{stg}	–40 to +100	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Frequency Range		BW	40	—	600	MHz
Power Gain	f = 50 MHz	G_p	21	21.5	22	dB
Power Gain	f = 600 MHz	G_p	21.7	—	23	dB
Slope	f = 40–600 MHz	S	0	—	1.8	dB
Gain Flatness (Peak to Valley)	f = 40–600 MHz	—	—	0.2	0.6	dB
Return Loss — Input/Output (Z_o = 75 Ohms)	f = 40–600 MHz	IRL/ORL	18	—	—	dB
Composite Second Order (V_{out} = +44 dBmV/Ch)	87–Channel FLAT	CSO_{87}	—	—	–56	dB
Cross Modulation Distortion (V_{out} = +44 dBmV/Ch, Fm = 55 MHz)	87–Channel FLAT	XMD_{87}	—	—	–56	dB
Composite Triple Beat (V_{out} = +44 dBmV/Ch)	87–Channel FLAT	CTB_{87}	—	—	–56	dB
Noise Figure	f = 50 MHz f = 600 MHz	NF	— —	— —	5 6	dB
DC Current (V_{DC} = 24 Vdc, T_C = 30°C)		I_{DC}	180	—	240	mA

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	——	1.775	——	45.08
B	——	1.085	——	27.56
C	——	0.840	——	21.34
D	0.018	0.022	0.46	0.56
E	0.465	0.510	11.81	12.95
F	0.300	0.325	7.62	8.25
G	0.100 BSC		2.54 BSC	
J	0.156 BSC		3.96 BSC	
K	0.315	0.355	8.00	8.50
L	1.00 BSC		25.40 BSC	
N	0.165 BSC		4.10 BSC	
P	0.100 BSC		2.54 BSC	
Q	0.148	0.168	3.76	4.27
R	——	0.595	——	15.11
S	1.500 BSC		38.10 BSC	
U	0.200 BSC		5.08 BSC	
V	0.280 BSC		7.11 BSC	
W	0.435	0.450	11.05	11.43

STYLE 1:
PIN 1. RF INPUT
2. GROUND
3. GROUND
4. DELETED
5. VDC
6. DELETED
7. GROUND
8. GROUND
9. RF OUTPUT

CASE 714–06
ISSUE K

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